

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer





FAN5400/FAN5401/FAN5402/FAN5403/FAN5404/FAN5405 USB-Compliant Single-Cell Li-Ion Switching Charger with USB-OTG Boost Regulator

Features

- Fully Integrated, High-Efficiency Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- Faster Charging than Linear
- Charge Voltage Accuracy: ±0.5% at 25°C

±1% from 0 to 125°C

- ±5% Input Current Regulation Accuracy
- ±5% Charge Current Regulation Accuracy
- 20 V Absolute Maximum Input Voltage
- 6 V Maximum Input Operating Voltage
- 1.25 A Maximum Charge Rate
- Programmable through High-Speed I²C Interface (3.4 Mb/s) with Fast Mode Plus Compatibility
 - Input Current
 - Fast-Charge / Termination Current
 - Charger Voltage
 - Termination Enable
- 3 MHz Synchronous Buck PWM Controller with Wide Duty Cycle Range
- Small Footprint 1 μH External Inductor
- Safety Timer with Reset Control
- 1.8 V Regulated Output from VBUS for Auxiliary Circuits
- Weak Input Sources Accommodated by Reducing Charging Current to Maintain Minimum VBUS Voltage
- Low Reverse Leakage to Prevent Battery Drain to VBUS
- 5 V, 300 mA Boost Mode for USB OTG for 2.5 to 4.5 V Battery Input

Applications

- Cell Phones, Smart Phones, PDAs
- Tablet, Portable Media Players
- Gaming Device, Digital Cameras

All trademarks are the property of their respective owners.

Description

The FAN5400 family (FAN540x) combines a highly integrated switch-mode charger, to minimize single-cell Lithium-ion (Li-ion) charging time from a USB power source, and a boost regulator to power a USB peripheral from the battery.

The charging parameters and operating modes are programmable through an I²C Interface that operates up to 3.4 Mbps. The charger and boost regulator circuits switch at 3 MHz to minimize the size of external passive components.

The FAN540X provides battery charging in three phases: conditioning, constant current, and constant voltage.

To ensure USB compliance and minimize charging time, the input current is limited to the value set through the I²C host. Charge termination is determined by a programmable minimum current level. A safety timer with reset control provides a safety backup for the I²C host.

The integrated circuit (IC) automatically restarts the charge cycle when the battery falls below an internal threshold. If the input source is removed, the IC enters a high-impedance mode with leakage from the battery to the input prevented. Charge status is reported back to the host through the I²C port. Charge current is reduced when the die temperature reaches 120°C.

The FAN540X can operate as a boost regulator on command from the system. The boost regulator includes a soft-start that limits inrush current from the battery.

The FAN540X is available in a 1.96 x 1.87 mm, 20-bump, 0.4 mm pitch, WLCSP package.

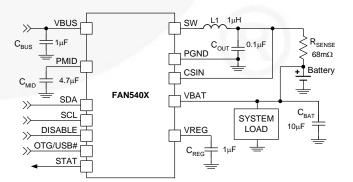


Figure 1. Typical Application (FAN5403-05 Pin Out)

Ordering Information

Part Number	Temperature Range	Package	PN Bits: IC_INFO[4:3]	Packing Method
FAN5400UCX	-40 to 85°C		01	Tape and Reel
FAN5401UCX	-40 to 85°C		00	Tape and Reel
FAN5402UCX	-40 to 85°C	20-Bump, Wafer- Level Chip-Scale	01	Tape and Reel
FAN5403UCX	-40 to 85°C	Package (WLCSP),	10	Tape and Reel
FAN5403BUCX ⁽¹⁾	-40 to 85°C	0.4 mm Pitch, Estimated Size: 1.96 x 1.87 mm	10	Tape and Reel
FAN5404UCX	-40 to 85°C		11	Tape and Reel
FAN5405UCX	-40 to 85°C		10	Tape and Reel
FAN5405BUCX ⁽¹⁾	-40 to 85°C		10	Tape and Reel

Note:

Table 1. Feature Comparison Summary

Part Number	PN Bits: REG3[4:3]	Slave Address	Automatic Charge	Special Charger ⁽²⁾	Safety Limits	Battery Absent Behavior	E2 Pin	VREG (E3 Pin)	
FAN5400	01	1101011	Yes	No	No	OFF	AUXPWR		
FAN5401	00	1101011	No	No	No	OFF	(Connect to VBAT)	`	PMID
FAN5402	01	1101011	Yes	No	No	ON		1	
FAN5403	10	1101011	Yes	Yes	Yes	OFF			
FAN5404	11	1101011	No	Yes	Yes	OFF	DISABLE	1.8V	
FAN5405	10	1101010	Yes	Yes	Yes	ON			

Note

Table 2. Recommended External Components

Component	Description	Vendor	Parameter	Тур.	Unit
L1	4 11 2007 4 2 4 2040	Murata: LQM2MPN1R0M	L	1.0	μΗ
LI	1 μH, 20%, 1.3 A, 2016	or Equivalent	DCR (Series R)	85	mΩ
Сват	10 μF, 20%, 6.3 V, X5R, 0603	Murata: GRM188R60J106M TDK: C1608X5R0J106M	С	10	μF
C _{MID}	4.7 μF, 10%, 6.3 V, X5R, 0603	Murata: GRM188R60J475K TDK: C1608X5R0J475K	C ⁽³⁾	4.7	μF
C _{BUS}	1.0 μF, 10%, 25 V, X5R, 0603	Murata GRM188R61E105K TDK:C1608X5R1E105M	С	1.0	μF

Note:

3. 6.3 V rating is sufficient for C_{MID} since PMID is protected from over-voltage surges on VBUS by Q3 (Figure 3).

^{1.} FAN5403BUCX and FAN5405BUCX Includes backside lamination

^{2.} Special charger is a current limited charger that is not a USB compliant source.

Block Diagram

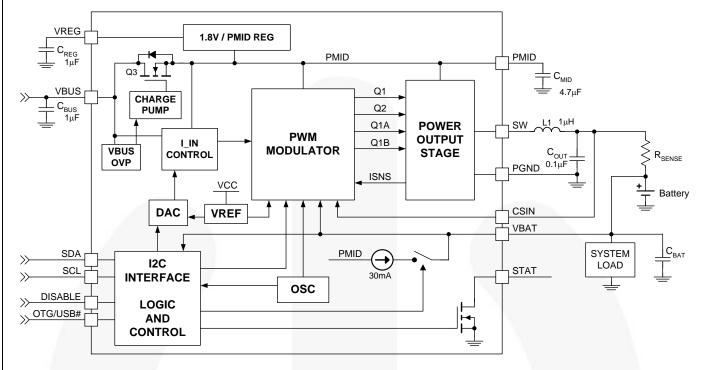


Figure 2. IC and System Block Diagram

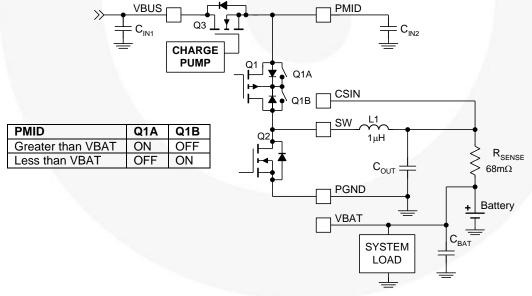
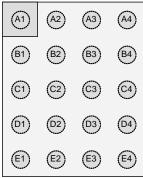


Figure 3. Power Stage

Pin Configuration



Top View

 G3
 G4

 G3
 G2

 G1
 G3

 G4
 G3

 G4
 G3

 G2
 G1

 G4
 G3

 G2
 G1

 G4
 G3

 G2
 G1

 G4
 G3

 G2
 G1

(A4)

(B4)

(A3)

(B3)

(A2)

(B2)

Bottom View

(A1)

(B1)

Figure 4. WLCSP-20 Pin Assignments

Pin Definitions

Pin#	Name	Part #	Description
A1, A2	VBUS	ALL	Charger Input Voltage and USB-OTG output voltage. Bypass with a 1 μF capacitor to PGND.
А3	NC	ALL	No Connect. No external connection is made between this pin and the IC's internal circuitry.
A4	SCL	ALL	I ² C Interface Serial Clock. This pin should not be left floating.
B1-B3	PMID	ALL	Power Input Voltage . Power input to the charger regulator, bypass point for the input current sense, and high-voltage input switch. Bypass with a minimum of 4.7 μ F, 6.3 V capacitor to PGND.
B4	SDA	ALL	I ² C Interface Serial Data. This pin should not be left floating.
C1-C3	SW	ALL	Switching Node. Connect to output inductor.
C4	STAT	ALL	Status . Open-drain output indicating charge status. The IC pulls this pin LOW when charge is in process.
D1-D3	PGND	ALL	Power Ground . Power return for gate drive and power transistors. The connection from this pin to the bottom of C_{MID} should be as short as possible.
D4	OTG	ALL	On-The-Go . Enables boost regulator in conjunction with OTG_EN and OTG_PL bits (see <i>Table 16</i>). On VBUS Power-On Reset (POR), this pin sets the input current limit for t _{15MIN} charging.
E1	CSIN	ALL	Current-Sense Input . Connect to the sense resistor in series with the battery. The IC uses this node to sense current into the battery. Bypass this pin with a 0.1 μ F capacitor to PGND.
E2	AUXPWR	FAN5400, FAN5401, FAN5402	Auxiliary Power. Connect to the battery pack to provide IC power during High-Impedance Mode. Bypass with a 1 μ F capacitor to PGND.
E2	DISABLE	FAN5403, FAN5404, FAN5405	Charge Disable . If this pin is HIGH, charging is disabled. When LOW, charging is controlled by the I ² C registers. When this pin is HIGH, the 15-minute timer is reset. This pin does not affect the 32-second timer.
E3	VREG	ALL	Regulator Output . Connect to a $1\mu F$ capacitor to PGND. This pin can supply up to 2 mA of DC load current. For FAN5400-FAN5402, the output voltage is PMID, which is limited to 6.5 V. For FAN5403-FAN5405, the output voltage is regulated to 1.8 V.
E4	VBAT	ALL	Battery Voltage . Connect to the positive (+) terminal of the battery pack. Bypass with a $0.1~\mu\text{F}$ capacitor to PGND if the battery is connected through long leads.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter	Min.	Max.	Unit	
M	VBUS Voltage	Continuous	-1.4	20.0	V	
V_{BUS}	Pulsed, 100 ms Maximum Non-Repetitive			20.0	V	
V _{STAT}	STAT Voltage		-0.3	16.0	V	
VI	PMID Voltage			7.0	V	
VI	SW, CSIN, VBAT, AUXPWR,	DISABLE Voltage	-0.3	7.0	V	
Vo	Voltage on Other Pins		-0.3	-0.3 6.5 ⁽⁴⁾		
dV _{BUS}	Maximum VBUS Slope above	e 5.5 V when Boost or Charger are Active		4	V/µs	
ESD	Electrostatic Discharge	Human Body Model per JESD22-A114	20	000	V	
E9D	Protection Level	Charged Device Model per JESD22-C101	5	00	V	
TJ	Junction Temperature		-40	+150	°C	
T _{STG}	Storage Temperature		-65	+150	°C	
TL	Lead Soldering Temperature,	10 Seconds	V.	+260	°C	

Note:

Lesser of 6.5 V or V_I + 0.3 V.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter			Max.	Units
V _{BUS}	Supply Voltage		4	6	V
V _{BAT(MAX)}	Maximum Battery Voltage when Boost enabled			4.5	V
_ dV _{BUS}	Negative VBUS Slew Rate during VBUS Short Circuit,	T _A ≤ 60°C		4	\// _{**} 0
- dt	C _{MID} ≤ 4.7 μF, see VBUS Short While Charging	T _A <u>></u> 60°C		2	V/μs
T _A	Ambient Temperature	emperature		+85	°C
TJ	Junction Temperature (see Thermal Regulation and Prote	ection section)	-30	+120	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperature T_A . For measured data, see Table 11.

Symbol	Parameter	Typical	Units
$\theta_{\sf JA}$	Junction-to-Ambient Thermal Resistance	60	°C/W
$\theta_{\sf JB}$	Junction-to-PCB Thermal Resistance	20	°C/W

Electrical Specifications

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A ; V_{BUS} =5.0 V; HZ_MODE ; QPA_MODE =0; (Charge Mode); QPA_MODE =0; (Charge Mode); (Charge Mode);

Symbol	Parameter	Condi	tions	Min.	Тур.	Max.	Units
Power Supp	lies						
		$V_{BUS} > V_{BUS(min)}, PW$	M Switching		10		mA
I_{VBUS}	VBUS Current	V _{BUS} > V _{BUS(min)} ; PWM Enabled, Not Switching (Battery OVP Condition); I_IN Setting=100 mA			2.5		mA
		0°C < T _J < 85°C, HZ V _{BAT} < V _{LOWV} , 32S M			63	90	μА
I _{LKG}	VBAT to VBUS Leakage Current	0°C < T _J < 85°C, HZ V _{BAT} =4.2 V, V _{BUS} =0			0.2	5.0	μА
1	Battery Discharge Current in High-	0°C < T _J < 85°C, HZ V _{BAT} =4.2 V	_MODE=1,			20	
I _{BAT}	Impedance Mode	FAN5403-05, DISAE 0°C < T _J < 85°C, V _B				10	μΑ
Charger Vol	tage Regulation						
	Charge Voltage Range			3.5		4.4	
V_{OREG}	Charge Voltage Assures	T _A =25°C		-0.5%		+0.5%	V
	Charge Voltage Accuracy	T _J =0 to 125°C		-1%		+1%	
Charging Cเ	urrent Regulation						,
	Output Charge Current Range	V _{LOWV} < V _{BAT} < V _{ORE} V _{BUS} > V _{SLP} , R _{SENSE}		550		1250	mA
	Charge Current Accuracy Across R _{SENSE}	20 mV <u><</u> V _{IREG} <u><</u>	FAN5400-02	95	100	105	
I _{OCHRG}		40 mV	FAN5403-05	92	97	102	%
		V _{IREG} > 40 mV	FAN5400-02	97	100	103	
		VIREG > 40 III V	FAN5403-05	94	97	100	
Weak Batter	y Detection						
	Weak Battery Threshold Range			3.4		3.7	V
V_{LOWV}	Weak Battery Threshold Accuracy			– 5		+5	%
	Weak Battery Deglitch Time	Rising Voltage, 2 m	/ Overdrive		30		ms
Logic Levels	s: DISABLE, SDA, SCL, OTG						
V_{IH}	High-Level Input Voltage			1.05			V
V_{IL}	Low-Level Input Voltage					0.4	V
I _{IN}	Input Bias Current	Input Tied to GND o	r V _{IN}		0.01	1.00	μΑ
Charge Tern	nination Detection						
	Termination Current Range	$V_{BAT} > V_{OREG} - V_{RCH}$ $R_{SENSE}=68 \text{ m}\Omega$, $V_{BUS} > V_{SLP}$,	50		400	mA
I _(TERM)	Tormination Current Assuras:	[V _{CSIN} – V _{BAT}] from 3 mV to 20 mV [V _{CSIN} – V _{BAT}] from 20 mV to 40 mV		-25		+25	0/
, ,	Termination Current Accuracy			- 5		+5	%
	Termination Current Deglitch Time	2 mV Overdrive			30		ms
1.8 V Linear	Regulator						
V_{REG}	1.8 V Regulator Output	I _{REG} from 0 to 2 mA,	FAN5403-05	1.7	1.8	1.9	V

Continued on the following page...

Electrical Specifications

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A ; V_{BUS} =5.0 V; HZ_MODE ; QPA_MODE =0; (Charge Mode); QPA_MODE =0; (Charge Mode); (Charge Mode);

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Input Power	Source Detection		•	· •	·	•
V _{IN(MIN)1}	VBUS Input Voltage Rising	To Initiate and Pass VBUS Validation		4.29	4.42	V
V _{IN(MIN)2}	Minimum VBUS during Charge	During Charging		3.71	3.94	V
t _{VBUS_VALID}	VBUS Validation Time			30		ms
Special Cha	rger (V _{BUS}) (FAN5403 – FAN5405)				•	
V_{SP}	Special Charger Setpoint Accuracy		-3		+3	%
Input Curren	nt Limit				•	
		I _{IN} Set to 100 mA	88	93	98	0
I _{INLIM}	Input Current Limit Threshold	I _{IN} Set to 500 mA	450	475	500	mA
V _{REF} Bias Ge	enerator		•		·	•
V	Bias Regulator Voltage	V _{BUS} > V _{IN(MIN)} or V _{BAT} > V _{BAT(MIN)}			6.5	V
V_{REF}	Short-Circuit Current Limit			20		mA
Battery Rech	harge Threshold		v			
V	Recharge Threshold	Below V _(OREG)	100	120	150	mV
V_{RCH}	Deglitch Time	V _{BAT} Falling Below V _{RCH} Threshold		130		ms
STAT Outpu	t					
V _{STAT(OL)}	STAT Output Low	I _{STAT} =10 mA			0.4	V
I _{STAT(OH)}	STAT High Leakage Current	V _{STAT} =5 V			1	μΑ
Battery Dete	ection			II.		
I _{DETECT}	Battery Detection Current before Charge Done (Sink Current) ⁽⁵⁾	Begins after Termination Detected		-0.80		mA
t _{DETECT}	Battery Detection Time	and V _{BAT} ≤ V _{OREG} −V _{RCH}		262		ms
Sleep Comp	arator		A			
V_{SLP}	Sleep-Mode Entry Threshold, V _{BUS} – V _{BAT}	$2.3 \text{ V} \leq \text{V}_{\text{BAT}} \leq \text{V}_{\text{OREG}}, \text{V}_{\text{BUS}} \text{ Falling}$	0	0.04	0.10	V
V _{SLP_EXIT}	Deglitch Time for VBUS Rising Above V _{SLP} + V _{SLP_EXIT}	Rising Voltage		30		ms
Power Switc	thes (see Figure 3)					
	Q3 On Resistance (VBUS to PMID)	I _{IN(LIMIT)} =500 mA		180	250	
$R_{DS(ON)}$	Q1 On Resistance (PMID to SW)			130	225	mΩ
	Q2 On Resistance (SW to GND)			150	225	
Charger PW	M Modulator					
f _{SW}	Oscillator Frequency		2.7	3.0	3.3	MHz
D _{MAX}	Maximum Duty Cycle				100	%
D _{MIN}	Minimum Duty Cycle			0		%
I _{SYNC}	Synchronous to Non-Synchronous Current Cut-Off Threshold ⁽⁶⁾	Low-Side MOSFET (Q2) Cycle-by- Cycle Current Limit		140		mA

Continued on the following page...

Electrical Specifications

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A ; V_{BUS} =5.0 V; HZ_MODE ; OPA_MODE =0; (Charge Mode); SCL, SDA, OTG=0 or 1.8 V; and typical values are for T_J =25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Boost Mode	Operation (OPA_MODE=1, HZ_MOI	DE=0)	1	•	•	•
M	Decet Output Valters at VIDLIC	$2.5~\text{V} < \text{V}_{\text{BAT}} < 4.5~\text{V},~\text{I}_{\text{LOAD}}$ from 0 to 200 mA	4.80	5.07	5.17	
V_{BOOST}	Boost Output Voltage at VBUS	$2.7 \text{ V} < \text{V}_{\text{BAT}} < 4.5 \text{ V}, \text{ I}_{\text{LOAD}} \text{ from 0 to}$ 200 mA	4.85	5.07	5.17	V
I _{BAT(BOOST)}	Boost Mode Quiescent Current	PFM Mode, V _{BAT} =3.6 V, I _{OUT} =0		140	300	μΑ
I _{LIMPK(BST)}	Q2 Peak Current Limit		1100	1380	1660	mA
11)/1.0	Minimum Battery Voltage for Boost	While Boost Active		2.42		V
UVLO _{BST}	Operation	To Start Boost Regulator		2.58	2.70	V
VBUS Load	Resistance					
Б	VIDLO 4- DOND Di-4-	Normal Operation		1500		ΚΩ
R _{VBUS}	VBUS to PGND Resistance	Charger Validation		100		Ω
Protection a	nd Timers					
VDLIC	VBUS Over-Voltage Shutdown	V _{BUS} Rising	6.09	6.29	6.49	V
VBUS _{OVP}	Hysteresis	V _{BUS} Falling		100		mV
I _{LIMPK(CHG)}	Q1 Cycle-by-Cycle Peak Current Limit	Charge Mode	Y	2.3		Α
V	Battery Short-Circuit Threshold	V _{BAT} Rising	1.95	2.00	2.05	V
V _{SHORT}	Hysteresis	V _{BAT} Falling		100		V
I _{SHORT}	Linear Charging Current	V _{BAT} < V _{SHORT}	20	30	40	mA
_	Thermal Shutdown Threshold ⁽⁷⁾	T _J Rising		145		°C
T _{SHUTDWN}	Hysteresis ⁽⁷⁾	T _J Falling		10		
T _{CF}	Thermal Regulation Threshold ⁽⁷⁾	Charge Current Reduction Begins		120		°C
t _{INT}	Detection Interval		//	2.1		S
4	32-Second Timer ⁽⁸⁾	Charger Enabled	20.5	25.2	28.0	
t ₃₂₈	52-Second Tiller	Charger Disabled	18.0	25.2	34.0	S
t _{15MIN}	15-Minute Timer	15-Minute Mode (FAN5400, FAN5402, FAN5404, FAN5405)	12.0	13.5	15.0	min
Δt_{LF}	Low-Frequency Timer Accuracy	Charger Inactive	-25		25	%

Notes:

- 5. Negative current is current flowing from the battery to V_{BUS} (discharging the battery).
- 6. Q2 always turns on for 60 ns, then turns off if current is below I_{SYNC}.
- 7. Guaranteed by design; not tested in production.
- 8. This tolerance (%) applies to all timers on the IC, including soft-start and deglitching timers.



I²C Timing Specifications

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
		Standard Mode			100	
	COL OLS ST. Francisco	Fast Mode			400	1.1.1_
f _{SCL}	SCL Clock Frequency	High-Speed Mode, C _B ≤ 100 pF			3400	kHz
		Frequency Fast Mode 40 High-Speed Mode, $C_B ≤ 100 \text{ pF}$ 340 High-Speed Mode, $C_B ≤ 400 \text{ pF}$ 170 Time between STOP T Conditions Standard Mode 4.7 Repeated START Fast Mode 1.3 Repeated START Standard Mode 4 Fast Mode 160 160 High-Speed Mode 1.3 160 Fast Mode 1.3 160 High-Speed Mode, $C_B ≤ 100 \text{ pF}$ 160 160 High-Speed Mode, $C_B ≤ 400 \text{ pF}$ 320 320 Standard Mode 4 4 4 Fast Mode 600 4 600 4 High-Speed Mode, $C_B ≤ 100 \text{ pF}$ 60 4 600 600 START Setup Time Fast Mode 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600 600	1700			
	Bus-Free Time between STOP	Standard Mode		4.7		
t _{BUF}	and START Conditions	Fast Mode		1.3		μS
		Standard Mode		4		μS
t _{HD;STA}	START or Repeated START	Fast Mode		600		ns
,	Hold Time	High-Speed Mode		160		ns
		• .		4.7		μS
		Fast Mode				μS
t_{LOW}	SCL LOW Period					ns
						ns
						μS
						ns
t _{HIGH}	SCL HIGH Period					ns
						ns
						μS
t _{SU;STA}	Repeated START Setup Time					ns
\$50;51A						ns
						110
t _{SU:DAT}	Data Setup Time					ns
SU;DAT	Data Setup Time					113
			0	10	2.45	
						με
t _{HD;DAT}	Data Hold Time					ns
						ns
				0.10		ns
t_{RCL}	SCL Rise Time	High-Speed Mode, C _B < 100 pF	20 +		80	ns
				10		
		High-Speed Mode, C _B ≤ 400 pF Standard Mode	20.	20	160	
		Fast Mode		0.1C _B	300	
t_{FCL}	SCL Fall Time		20 +		300	ns
		High-Speed Mode, C _B ≤ 100 pF		10	40	-
		High-Speed Mode, C _B ≤ 400 pF	20.	20	80	
	SDA Rise Time	Standard Mode		0.1C _B	1000	-
t _{RDA}	Rise Time of SCL after a Repeated START Condition	Fast Mode	20 +	0.1C _B	300	ns
t _{RCL1}	and after ACK Bit	High-Speed Mode, C _B ≤ 100 pF		10	80	
		High-Speed Mode, C _B ≤ 400 pF		20	160	

Continued on the following page...

I²C Timing Specifications

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
		Standard Mode	20 +	0.1C _B	300	
t _{FDA}	SDA Fall Time	Fast Mode	20 +	20 + 0.1C _B		1
	SDA Fall Time	High-Speed Mode, C _B ≤ 100 pF		10	80	ns
		High-Speed Mode, C _B ≤ 400 pF		20	160	
		Standard Mode		4		μS
t _{SU;STO}	Stop Condition Setup Time	Fast Mode		600		ns
		High-Speed Mode		160		ns
Св	Capacitive Load for SDA, SCL				400	pF

Timing Diagrams

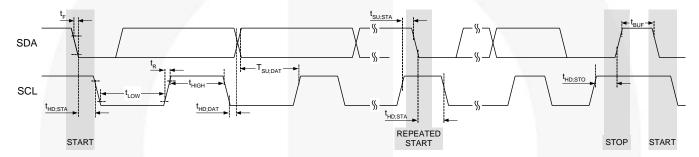


Figure 5. I²C Interface Timing for Fast and Slow Modes

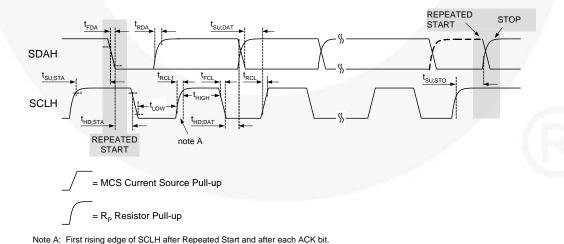
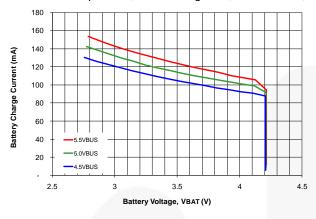


Figure 6. I²C Interface Timing for High-Speed Mode

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.



900 800 700 Current (mA) 600 500 **Battery Charge** 400 300 200 5.0VBUS 100 4.5VBUS 2.5 3.5 4 4.5 Battery Voltage, VBAT (V)

Figure 7. Battery Charge Current vs. V_{BUS} with I_{INLIM} =100 mA

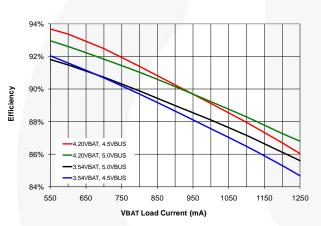


Figure 8. Battery Charge Current vs. V_{BUS} with I_{INLIM}=500 mA

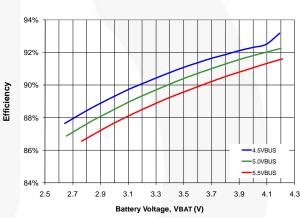


Figure 9. Charger Efficiency, No I_{INLIM}, I_{OCHARGE}=1,250 mA

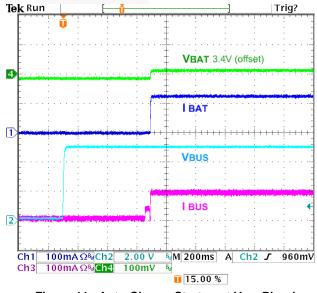


Figure 10. Charger Efficiency vs. V_{BUS}, I_{INLIM}=500 mA

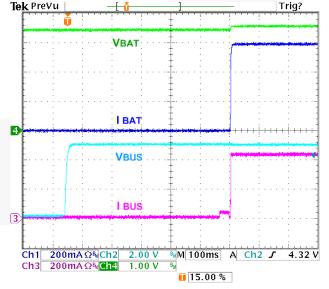
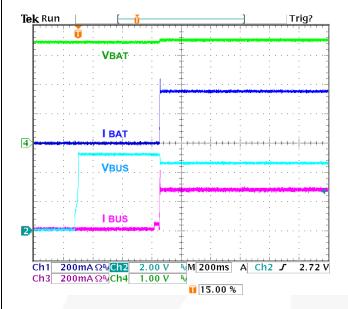


Figure 11. Auto-Charge Startup at V_{BUS} Plug-in, I_{INLIM}=100 mA, OTG=1, V_{BAT}=3.4 V

Figure 12. Auto-Charge Startup at V_{BUS} Plug-in, I_{INLIM}=500 mA, OTG=1, V_{BAT}=3.4 V

Charge Mode Typical Characteristics

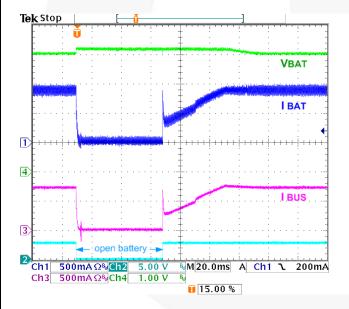
Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.



Tek Stop | VBAT | IBAT | IBAT | IBUS | IBUS

Figure 13. AutoCharge Startup with 300 mA Limited Charger / Adaptor, I_{INLIM}=500 mA, OTG=1, V_{BAT}=3.4 V

Figure 14. Charger Startup with HZ_MODE Bit Reset, I_{INLIM} =500 mA, $I_{OCHARGE}$ =950 mA, OREG=4.2 V, V_{BAT} =3.6 V



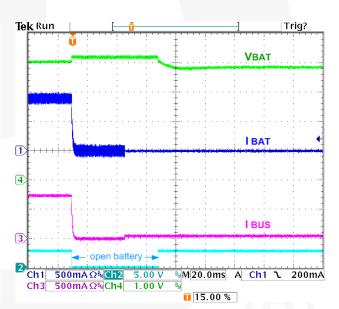
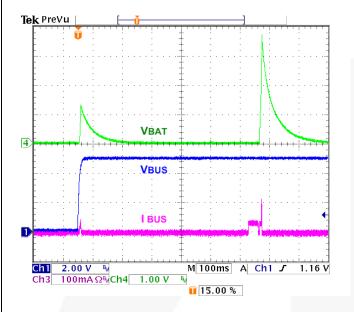


Figure 15. Battery Removal / Insertion during Charging, V_{BAT} =3.9 V, $I_{OCHARGE}$ =950 mA, No I_{INLIM} , TE=0

Figure 16. Battery Removal / Insertion during Charging, V_{BAT} =3.9 V, $I_{OCHARGE}$ =950 mA, No I_{INLIM} , TE=1

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.



Trig?

VBAT

VBUS

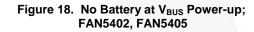
I BUS

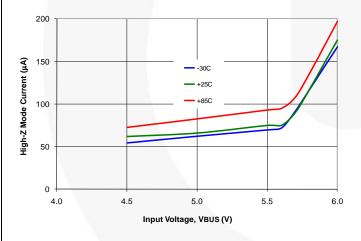
Ch1 2.00 V %

Ch2 100 mA Ω% Ch4 1.00 V %

I 15.00 %

Figure 17. No Battery at V_{BUS} Power-up; FAN5400, FAN5403





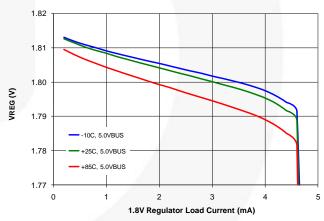
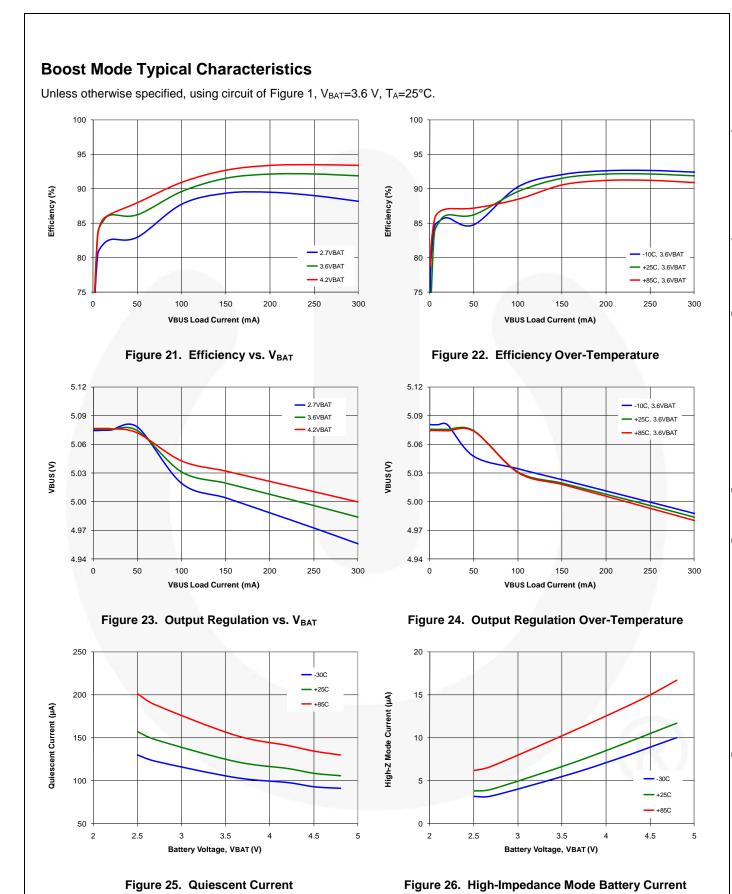


Figure 19. VBUS Current in High-Impedance Mode with Battery Open

Figure 20. V_{REG} 1.8 V Output Regulation



Boost Mode Typical Characteristics

Unless otherwise specified, using circuit of Figure 1, V_{BAT}=3.6 V, T_A=25°C.

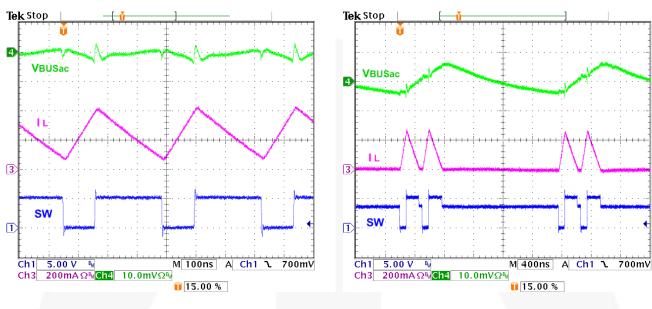


Figure 27. Boost PWM Waveform

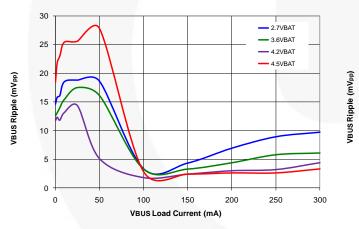


Figure 29. Output Ripple vs. V_{BAT}

Figure 28. Boost PFM Waveform

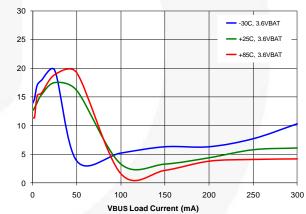


Figure 30. Output Ripple vs. Temperature

Boost Mode Typical Characteristics

Unless otherwise specified, using circuit of Figure 1, V_{BAT}=3.6 V, T_A=25°C.

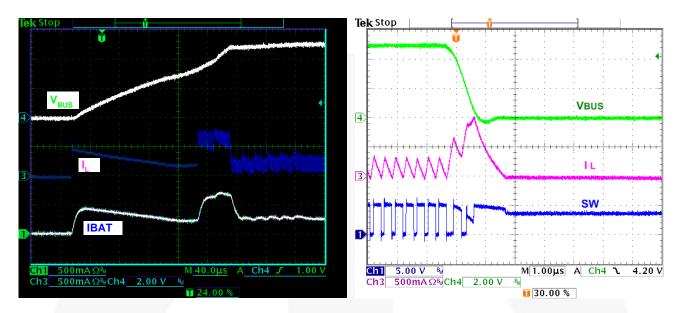


Figure 31. Startup, 3.6 $V_{BAT},$ 44 Ω Load, Additional 10 $\mu F,$ X5R Across V_{BUS}

Figure 32. V_{BUS} Fault Response, 3.6 V_{BAT}

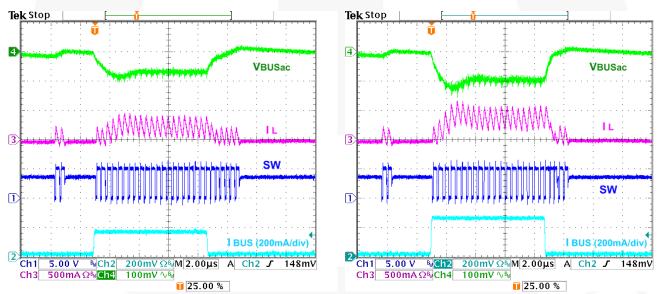


Figure 33. Load Transient, 5-155-5 mA, t_R=t_F=100 ns

Figure 34. Load Transient, 5-255-5 mA, t_R=t_F=100 ns

Circuit Description / Overview

When charging batteries with a current-limited input source, such as USB, a switching charger's high efficiency over a wide range of output voltages minimizes charging time.

FAN540X combines a highly integrated synchronous buck regulator for charging with a synchronous boost regulator, which can supply 5 V to USB On-The-Go (OTG) peripherals. The regulator employs synchronous rectification for both the charger and boost regulators to maintain high efficiency over a wide range of battery voltages and charge states.

The FAN540X has three operating modes:

- Charge Mode: Charges a single-cell Li-ion or Li-polymer battery.
- Boost Mode: Provides 5 V power to USB-OTG with an integrated synchronous rectification boost regulator using the battery as input.
- High-Impedance Mode:
 Both the boost and charging circuits are OFF in this mode. Current flow from VBUS to the battery or from the battery to VBUS is blocked in this mode. This mode consumes very little current from VBUS or the battery.

Note: Default settings are denoted by **bold typeface**.

Charge Mode

In Charge Mode, FAN540X employs four regulation loops:

- Input Current: Limits the amount of current drawn from VBUS. This current is sensed internally and can be programmed through the I²C interface.
- 2. Charging Current: Limits the maximum charging current. This current is sensed using an external R_{SENSE} resistor.
- 3. Charge Voltage: The regulator is restricted from exceeding this voltage. As the internal battery voltage rises, the battery's internal impedance and R_{SENSE} work in conjunction with the charge voltage regulation to decrease the amount of current flowing to the battery. Battery charging is completed when the voltage across R_{SENSE} drops below the I_{TERM} threshold.
- Temperature: If the IC's junction temperature reaches 120°C, charge current is continuously reduced until the IC's temperature stabilizes at 120°C.

In addition, the FAN5403-05 employ an additional loop to limit the amount of drop on VBUS to a programmable voltage (V_{SP}) to accommodate "special chargers" that limit current to a lower current than might be available from a "normal" USB wall charger.

Battery Charging Curve

If the battery voltage is below V_{SHORT} , a linear current source pre-charges the battery until V_{BAT} reaches V_{SHORT} . The PWM charging circuit is then started and the battery is charged

with a constant current if sufficient input power is available. The current slew rate is limited to prevent overshoot.

The FAN540X is designed to work with a current-limited input source at VBUS. During the current regulation phase of charging, I_{INLIM} or the programmed charging current limits the amount of current available to charge the battery and power the system. The effect of I_{INLIM} on I_{CHARGE} can be seen in Figure 36.

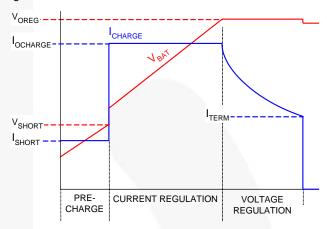


Figure 35. Charge Curve, ICHARGE Not Limited by IINLIM

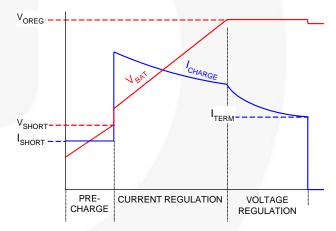


Figure 36. Charge Curve, I_{INLIM} Limits I_{CHARGE}

Assuming that V_{OREG} is programmed to the cell's fully charged "float" voltage, the current that the battery accepts with the PWM regulator limiting its output (sensed at VBAT) to V_{OREG} declines, and the charger enters the voltage regulation phase of charging. When the current declines to the programmed I_{TERM} value, the charge cycle is complete. Charge current termination can be disabled by resetting the TE bit (REG1[3]).

The charger output or "float" voltage can be programmed by the OREG bits from 3.5 V to 4.44 V in 20 mV increments, as shown in Table 3.

Table 3. OREG Bits (OREG[7:2]) vs. Charger V_{OUT} (V_{OREG}) Float Voltage

(V _{OREG}) Float Voltage				
Decimal	Hex	VOREG		
0	00	3.50		
1	01	3.52		
2	02	3.54		
3	03	3.56		
4	04	3.58		
5	05	3.60		
6	06	3.62		
7	07	3.64		
8	08	3.66		
9	09	3.68		
10	0A	3.70		
11	0B	3.72		
12	0C	3.74		
13	0D	3.76		
14	0E	3.78		
15	0F	3.80		
16	10	3.82		
17	11	3.84		
18	12	3.86		
19	13	3.88		
20	14	3.90		
21	15	3.92		
22	16	3.94		
23	17	3.96		
24	18	3.98		
25	19	4.00		
26	1A	4.02		
27	1B	4.04		
28	1C	4.06		
29	1D	4.08		
30	1E	4.10		

Decimal	Hex	VOREG
32	20	4.14
33	21	4.16
34	22	4.18
35	23	4.20
36	24	4.22
37	25	4.24
38	26	4.26
39	27	4.28
40	28	4.30
41	29	4.32
42	2A	4.34
43	2B	4.36
44	2C	4.38
45	2D	4.40
46	2E	4.42
47	2F	4.44
48	30	4.44
49	31	4.44
50	32	4.44
51	33	4.44
52	34	4.44
53	35	4.44
54	36	4.44
55	37	4.44
56	38	4.44
57	39	4.44
58	3A	4.44
59	3B	4.44
60	3C	4.44
61	3D	4.44
62	3E	4.44

The following charging parameters can be programmed by the host through I²C:

Table 4. Programmable Charging Parameters

Parameter	Name	Register
Output Voltage Regulation	Voreg	REG2[7:2]
Battery Charging Current Limit	I _{OCHRG}	REG4[6:4]
Input Current Limit	I _{INLIM}	REG1[7:6]
Charge Termination Limit	I _{TERM}	REG4[2:0]
Weak Battery Voltage	V_{LOWV}	REG1[5:4]

A new charge cycle begins when one of the following occurs:

- The battery voltage falls below V_{OREG} V_{RCH}
- VBUS Power On Reset (POR) clears and the battery voltage is below the weak battery threshold (V_{LOWV}).
 This occurs for all versions except the FAN5401.
- CE or HZ_MODE is reset through I²C write to CONTROL1 (R1) register.

Charge Current Limit (I_{OCHARGE})

Table 5. I_{OCHARGE} (REG4 [6:4]) Current as Function of I_{OCHARGE} Bits and R_{SENSE} Resistor Values

DEC	DEC BIN		V _{RSENSE}	I _{OCHARGE} (mA)		
DEC	DIN	HEX	(mV)	68 mΩ	100 m Ω	
0	000	00	37.4	550	374	
1	001	01	44.2	650	442	
2	010	02	51.0	750	510	
3	011	03	57.8	850	578	
4	100	04	64.6	950	646	
5	101	05	71.4	1050	714	
6	110	06	78.2	1150	782	
7	111	07	85.0	1250	850	

Termination Current Limit

Current charge termination is enabled when TE (REG1[3])=1. Typical termination current values are given in Table 6.

Table 6. I_{TERM} Current as Function of I_{TERM} Bits (REG4[2:0]) and R_{SENSE} Resistor Values

	 ,					
	FAN5400 - FAN5402			FAN540	03 - FA	N5405
	. V _{RSENSE}	I _{TERM} (mA)		V _{RSENSE}	I _{TERM} (mA)	
I _{TERM}	(mV)	68 mΩ	100 mΩ	(mV)	68 mΩ	100 mΩ
0	3.4	50	34	3.3	49	33
1	6.8	100	68	6.6	97	66
2	10.2	150	102	9.9	146	99
3	13.6	200	136	13.2	194	132
4	17.0	250	170	16.5	243	165
5	20.4	300	204	19.8	291	198
6	23.8	350	238	23.1	340	231
7	27.2	400	272	26.4	388	264

When the charge current falls below I_{TERM} for a period of 32 ms; PWM charging stops and the STAT bits change to READY (00) for about 500 ms while the IC determines whether the battery and charging source are still connected. The STAT bits then change to CHARGE DONE (10), provided the battery and charger are still connected.

PWM Controller in Charge Mode

The IC uses a current-mode PWM controller to regulate the output voltage and battery charge currents. The synchronous rectifier (Q2) has a negative current limit that turns off Q2 at 140 mA to prevent current flow from the battery.

Safety Timer

This section references Figure 41 and Figure 42.

At the beginning of charging, the IC starts a 15-minute timer ($t_{15\text{MIN}}$). When this timer times out, charging is terminated. Writing to any register through I²C stops and resets the $t_{15\text{MIN}}$ timer, which in turn starts a 32-second timer ($t_{32\text{S}}$). Setting the TMR_RST bit (REG0[7]) resets the $t_{32\text{S}}$ timer. If the $t_{32\text{S}}$ timer times out, charging is terminated, the registers are set to their default values, and charging resumes using the default values with the $t_{15\text{MIN}}$ timer running.

Normal charging is controlled by the host with the t_{32S} timer running to ensure that the host is alive. Charging with the $t_{15\text{MIN}}$ timer running is used for charging that is unattended by the host. If the $t_{15\text{MIN}}$ timer expires, the IC turns off the charger, sets the $\overline{\text{CE}}$ bit, and indicates a timer fault (110) on the FAULT bits (REG0[2:0]). This sequence prevents overcharge if the host fails to reset the t_{32S} timer.

V_{BUS} POR / Non-Compliant Charger Rejection

When the IC detects that V_{BUS} has risen above $V_{IN(MIN)1}$ (4.4 V), the IC applies a 110 Ω load from VBUS to GND. To clear the VBUS POR (Power-On-Reset) and begin charging, VBUS must remain above $V_{IN(MIN)1}$ and below VBUS_{OVP} for t_{VBUS_VALID} (30 ms) before the IC initiates charging. The VBUS validation sequence always occurs before charging is initiated or re-initiated (for example, after a VBUS OVP fault or a V_{RCH} recharge initiation).

 $t_{\text{VBUS_VALID}}$ ensures that unfiltered 50 / 60 Hz chargers and other non-compliant chargers are rejected.

USB-Friendly Boot Sequence

For all versions except FAN5401, FAN5404

At VBUS POR, when the battery voltage is above the weak battery threshold (V_{LOWV}), the IC operates in accordance with its I2C register settings. If VBAT < VLOWV, the IC sets all registers to their default values and enables the charger using an input current limit controlled by the OTG pin (100 mA if OTG is LOW and 500 mA if OTG is HIGH). This feature can revive a battery whose voltage is too low to ensure reliable host operation. Charging continues in the absence of host communication even after the battery has reached Voreg, whose default value is 3.54 V, and the charger remains active until t_{15MIN} times out. Once the host processor begins writing to the IC, charging parameters are set by the host, which must continually reset the tags timer to continue charging using the programmed charging parameters. If t₃₂₈,times out, the register defaults are loaded, the FAULT bits are set to 110, STAT is pulsed HIGH, and charging continues with default charge parameters.

The FAN5401 and FAN5404 do not automatically initiate charging at VBUS POR. Instead, they wait for the host to initiate charging through I²C commands.

Input Current Limiting

To minimize charging time without overloading VBUS current limitations, the IC's input current limit can be programmed by the I_{INLIM} bits (REG1[7:6]).

Table 7. Input Current Limit

I _{INLIM} REG1[7:6]	Input Current Limit
00	100 mA
01	500 mA
10	800 mA
11	No limit

For all versions except the FAN5401 and FAN5404, the OTG pin establishes the input current limit when $t_{15\text{MIN}}$ is running. For the FAN5401 and FAN5404, no charging occurs automatically at VBUS POR, so the input current limit is established by the I_{INLIM} bits.

Flow Charts

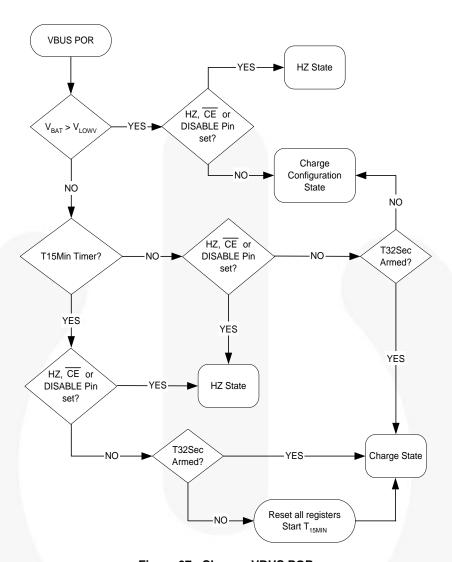
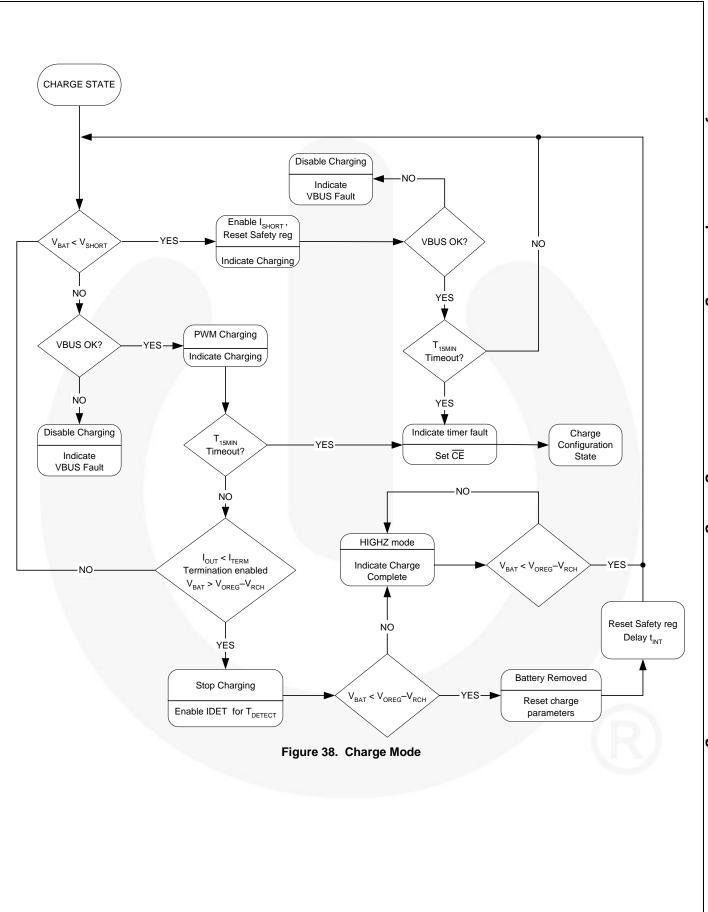


Figure 37. Charger VBUS POR



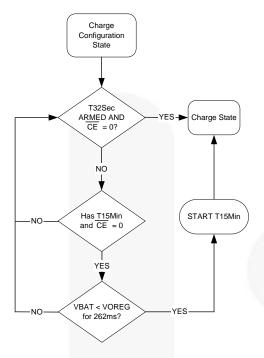


Figure 39. Charge Configuration

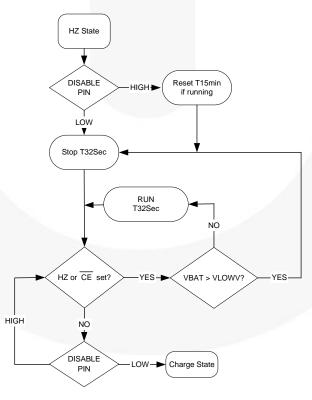


Figure 40. HZ-State

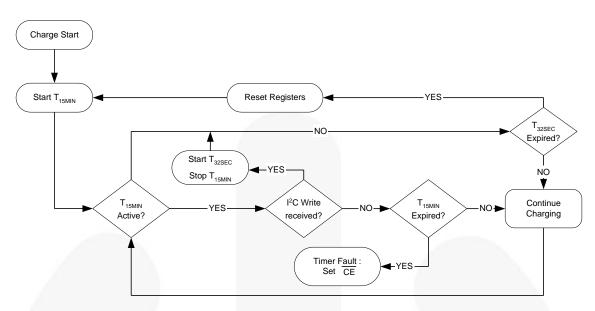


Figure 41. Timer Flow Chart for FAN5400, FAN5402, FAN5403, FAN5405

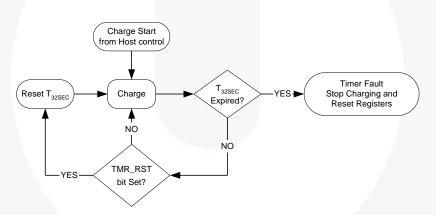


Figure 42. Timer Flow Chart for FAN5401, FAN5404

Special Charger

FAN5403-05 Only

The FAN5403, FAN5404, and FAN5405 have additional functionality to limit input current in case a current-limited "special charger" is supplying VBUS. The FAN5403-05 slowly increases the charging current until either:

I_{INLIM} or I_{OCHARGE} is reached

or

V_{BUS}=V_{SP}.

If V_{BUS} collapses to V_{SP} when the current is ramping up, the FAN5403-05 charge with an input current that keeps $V_{BUS}=V_{SP}$. When the V_{SP} control loop is limiting the charge current, the SP bit (REG5[4]) is set.

Table 8. V_{SP} as Function of SP Bits (REG5[2:0])

S			
DEC	BIN	HEX	V _{SP}
0	000	00	4.213
1	001	01	4.293
2	010	02	4.373
3	011	03	4.453
4	100	04	4.533
5	101	05	4.613
6	110	06	4.693
7	111	07	4.773

Safety Settings

FAN5403-FAN5405 Only

The FAN5403-05 contain a SAFETY register (REG6) that prevents the values in OREG (REG2[7:2]) and IOCHARGE (REG4[6:4]) from exceeding the values of the VSAFE and ISAFE values.

After V_{BAT} exceeds V_{SHORT}, the SAFETY register is loaded with its default value and may be written only before any other register is written. After writing to any other register, the SAFETY register is locked until V_{BAT} falls below V_{SHORT}.

The ISAFE (REG6[6:4]) and VSAFE (REG6[3:0]) registers establish values that limit the maximum values of $I_{OCHARGE}$ and V_{OREG} used by the control logic. If the host attempts to write a value higher than VSAFE or ISAFE to OREG or IOCHARGE, respectively; the VSAFE, ISAFE value appears as the OREG, IOCHARGE register value, respectively.

Table 9. I_{SAFE} (I_{OCHARGE} Limit) as Function of ISAFE Bits (REG6[6:4])

ISAFE	ISAFE (REG6[6:4])				
DEC	DIN	HEX	\/ (m\/)	I _{SAFE}	(mA)
DEC	BIN		BIN HEX VRSENSI	V _{RSENSE} (mV)	68 mΩ
0	000	00	37.4	550	374
1	001	01	44.2	650	442
2	010	02	51.0	750	510
3	011	03	57.8	850	578
4	100	04	64.6	950	646
5	101	05	71.4	1050	714
6	110	06	78.2	1150	782
7	111	07	85.0	1250	850

Table 10. V_{SAFE} (V_{OREG} Limit) as Function of VSAFE Bits (REG6[3:0])

VSAF	E (REG	6[3:0])		
DEC	BIN	HEX	Max. OREG (REG2[7:2])	VOREG Max.
0	0000	00	100011	4.20
1	0001	01	100100	4.22
2	0010	02	100101	4.24
3	0011	03	100110	4.26
4	0100	04	100111	4.28
5	0101	05	101000	4.30
6	0110	06	101001	4.32
7	0111	07	101010	4.34
8	1000	08	101011	4.36
9	1001	09	101100	4.38
10	1010	0A	101101	4.40
11	1011	0B	101110	4.42
12	1100	0C	101111	4.44
13	1101	0D	110000	4.44
14	1110	0E	110001	4.44
15	1111	0F	110010	4.44

Thermal Regulation and Protection

When the IC's junction temperature reaches T_{CF} (about 120°C), the charger reduces its output current to 550 mA to prevent overheating. If the temperature increases beyond $T_{SHUTDOWN}$; charging is suspended, the FAULT bits are set to 101, and STAT is pulsed HIGH. In Suspend Mode, all timers stop and the state of the IC's logic is preserved. Charging resumes at programmed current after the die cools to about 120°C.

Additional θ_{JA} data points, measured using the FAN540X evaluation board, are given in Table 11 (measured with T_A =25°C). Note that as power dissipation increases, the effective θ_{JA} decreases due to the larger difference between the die temperature and its ambient.

Table 11. FAN5400 Evaluation Board Measured θ_{JA}

Power (W)	θυΑ
0.504	54°C / W
0.844	50°C / W
1.506	46°C / W

Charge Mode Input Supply Protection

Sleep Mode

When V_{BUS} falls below V_{BAT} + V_{SLP} , and V_{BUS} is above $V_{IN(MIN)}$, the IC enters Sleep Mode to prevent the battery from draining into VBUS. During Sleep Mode, reverse current is disabled by body switching Q1.

Input Supply Low-Voltage Detection

The IC continuously monitors VBUS during charging. If V_{BUS} falls below $V_{IN(MIN)}$, the IC:

- 1. Terminates charging
- Pulses the STAT pin, sets the STAT bits to 11, and sets the FAULT bits to 011.

If V_{BUS} recovers above the $V_{\text{IN(MIN)}}$ rising threshold after time t_{INT} (about two seconds), the charging process is repeated. This function prevents the USB power bus from collapsing or oscillating when the IC is connected to a suspended USB port or a low-current-capable OTG device.

Input Over-Voltage Detection

When the V_{BUS} exceeds VBUS_{OVP}, the IC:

- 1. Turns off Q3
- 2. Suspends charging
- Sets the FAULT bits to 001, sets the STAT bits to 11, and pulses the STAT pin.

When V_{BUS} falls about 150 mV below VBUS_{OVP}, the fault is cleared and charging resumes after V_{BUS} is revalidated (see VBUS POR / Non-Compliant Charger Rejection).

VBUS Short While Charging

If VBUS is shorted with a very low impedance while the IC is charging with $I_{\rm INLIMIT}{=}100$ mA, the IC may not meet datasheet specifications until power is removed. To trigger this condition, $V_{\rm BUS}$ must be driven from 5 V to GND with a high slew rate. Achieving this slew rate requires a 0 Ω short to the USB cable less than 10cm from the connector.

Charge Mode Battery Detection & Protection

VBAT Over-Voltage Protection

The OREG voltage regulation loop prevents V_{BAT} from overshooting the OREG voltage by more than 50 mV when the battery is removed. When the PWM charger runs with no battery, the TE bit is not set and a battery is inserted that is charged to a voltage higher than V_{OREG} ; PWM pulses stop. If no further pulses occur for 30 ms, the IC sets the FAULT bits to 100, sets the STAT bits to 11, and pulses the STAT pin.

Battery Detection During Charging

The IC can detect the presence, absence, or removal of a battery if the termination bit (TE) is set. During normal charging, once V_{BAT} is close to V_{OREG} and the termination charge current is detected, the IC terminates charging and sets the STAT bits to 10. It then turns on a discharge current, I_{DETECT} , for I_{DETECT} . If V_{BAT} is still above $V_{\text{OREG}}-V_{\text{RCH}}$, the battery is present and the IC sets the FAULT bits to 000. If V_{BAT} is below $V_{\text{OREG}}-V_{\text{RCH}}$, the battery is absent and the IC:

- Sets the registers to their default values.
- 2. Sets the FAULT bits to 111.
- Resumes charging with default values after t_{INT}.

Battery Short-Circuit Protection

If the battery voltage is below the short-circuit threshold (V_{SHORT}); a linear current source, I_{SHORT} , supplies V_{BAT} until $V_{BAT} > V_{SHORT}$.

Battery Detection During Power-up

For FAN5400 and FAN5403

At VBUS POR, a 5 k Ω load is applied to VBAT for 500 ms to discharge any residual system capacitance in case the battery is absent. If $V_{BAT} < V_{SHORT}$, linear charging commences. When V_{BAT} rises above V_{SHORT} , PWM charging proceeds with the float voltage (OREG) temporarily set to 4 V. If the battery voltage exceeds 3.7 V within 32 ms of the beginning of PWM charging, the battery is absent. If battery absent is detected:

- 1. High-Impedance Mode is entered.
- 2. FAULT bits are set to 111.
- 3. The t_{15MIN} timer is disabled until VBUS is removed.

If V_{BAT} remains below 3.7 V during the initial 32 ms period, the float voltage returns to the OREG register setting and PWM charging continues.

System Operation with No Battery

The FAN5402 and FAN5405 continue charging after VBUS POR with the default parameters, regulating the V_{BAT} line to 3.54 V until the host processor issues commands or the 15-minute timer expires. In this way, the FAN5402 and FAN5405 can start the system without a battery.

The FAN540X soft-start function can interfere with the system supply with battery absent. The soft-start activates whenever $V_{\rm OREG},\ I_{\rm INLIM},\ {\rm or}\ I_{\rm OCHARGE}$ are set from a lower to higher value. During soft-start, the $I_{\rm IN}$ limit drops to 100 mA for about 1 ms unless $I_{\rm INLIM}$ is set to 11 (no limit). This could cause the system processor to fail to start. To avoid this behavior, use the following sequence.

- Set the OTG pin HIGH. When VBUS is plugged in, I_{INLIM} is set to 500 mA until the system processor powers up and can set parameters through I²C.
- 2. Program the Safety Register.
- 3. Set I_{INLIM} to 11 (no limit).
- 4. Set OREG to the desired value (typically 4.18).
- 5. Reset the IOLEVEL bit, then set IOCHARGE.
- 6. Set I_{INLIM} to 500mA if a USB source is connected.

During the initial system startup, while the charger IC is being programmed, the system current is limited to 325 mA for 1ms during steps 4 and 5. This is the value of the soft-start I_{CHARGE} current used when I_{INLIM} is set to No Limit.

If the system is powered up without a battery present, the CV bit should be set. When a battery is inserted, the CV bit is cleared.

Charger Status / Fault Status

The STAT pin indicates the operating condition of the IC and provides a fault indicator for interrupt driven systems.

Table 12. STAT Pin Function

EN_STAT	Charge State	STAT Pin
0	X	OPEN
Х	Normal Conditions	OPEN
1	Charging	LOW
Х	Fault (Charging or Boost)	128μs Pulse, then OPEN

The FAULT bits (R0[2:0]) indicate the type of fault in Charge Mode (see Table 13).

Table 13. Fault Status Bits During Charge Mode

F	Fault Bit		Fault Description
B2	B1	В0	Fault Description
0	0	0	Normal (No Fault)
0	0	1	VBUS OVP
0	1	0	Sleep Mode
0	1	1	Poor Input Source
1	0	0	Battery OVP
1	0	1	Thermal Shutdown
1	1	0	Timer Fault
1	1	1	No Battery

Charge Mode Control Bits

Setting either HZ_MODE or CE through I 2 C disables the charger and puts the IC into High-Impedance Mode and resets t_{32S} . If $V_{BAT} < V_{LOWV}$ while in High-Impedance Mode, t_{32S} begins running and, when it overflows, all registers (except SAFETY) reset, which enables t_{15MIN} charging on versions with the 15-minute timer.

When t_{15MIN} overflows, the IC sets the CE bit and the IC enters High-Impedance Mode. If $\overline{\text{CE}}$ was set by t_{15MIN} overflow, a new charge cycle can only be initiated through I²C or VBUS POR.

Setting the RESET bit clears all registers. If HZ_MODE or $\overline{\text{CE}}$ bits were set when the RESET bit is set, these bits are also cleared, but the t_{32S} timer is not started, and the IC remains in High-Impedance Mode.

Table 14. FAN5403–FAN5405 DISABLE Pin and $\overline{\text{CE}}$ Bit Functionality

Charging	DISABLE Pin	CE	HZ_MODE
ENABLE	0	0	0
DISABLE	X	1	X
DISABLE	X	Х	1
DISABLE	1	Х	X

Raising the DISABLE pin stops t_{32S} from advancing, but does not reset it. If the DISABLE pin is raised during t_{15MIN} charging, the t_{15MIN} timer is reset.

Operational Mode Control

OPA_MODE (REG1[0]) and the HZ_MODE (REG1[1]) bits in conjunction with the FAULT state define the operational mode of the charger.

Table 15. Operation Mode Control

HZ_MODE	OPA_MODE	FAULT	Operation Mode
0	0	0	Charge
0	X	1	Charge Configure
0	1	0	Boost
1	Х	Х	High Impedance

The IC resets the OPA_MODE bit whenever the boost is deactivated, whether due to a fault or being disabled by setting the HZ_MODE bit.

Boost Mode

Boost Mode can be enabled if the IC is in 32-Second Mode with the OTG pin and OPA_MODE bits as indicated in Table 16. The OTG pin ACTIVE state is 1 if OTG_PL=1 and 0 when OTG PL=0.

If boost is active using the OTG pin, Boost Mode is initiated even if the HZ_MODE=1. The HZ_MODE bit overrides the OPA MODE bit.

Table 16. Enabling Boost

OTG_EN	OTG Pin	HZ_ MODE	OPA_ MODE	BOOST
1	ACTIVE	Х	Х	Enabled
Х	Х	0	1	Enabled
X	ACTIVE	X	0	Disabled
0	Х	1	Х	Disabled
1	ACTIVE	1	1	Disabled
0	ACTIVE	0	0	Disabled

To remain in Boost Mode, the TMR_RST must be set by the host before the t_{32S} timer times out. If t_{32S} times out in Boost Mode; the IC resets all registers, pulses the STAT pin, sets the FAULT bits to 110, and resets the BOOST bit. VBUS POR or reading R0 clears the fault condition.

Boost PWM Control

The IC uses a minimum on-time and computed minimum off-time to regulate VBUS. The regulator achieves excellent transient response by employing current-mode modulation. This technique causes the regulator to exhibit a load line. During PWM Mode, the output voltage drops slightly as the input current rises. With a constant V_{BAT} , this appears as a constant output resistance.

The "droop" caused by the output resistance when a load is applied allows the regulator to respond smoothly to load transients with no undershoot from the load line. This can be seen in Figure 33 and Figure 43.

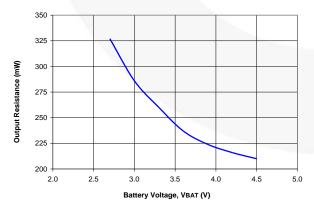


Figure 43. Output Resistance (ROUT)

 V_{BUS} as a function of I_{LOAD} can be computed when the regulator is in PWM Mode (continuous conduction) as:

$$V_{OUT} = 5.07 - R_{OUT} \bullet I_{LOAD}$$
 EQ. 1

At V_{BAT} =3.3 V, and I_{LOAD} =200 mA, V_{BUS} would drop to:

$$V_{OLIT} = 5.07 - 0.26 \bullet 0.2 = 5.018V$$
 EQ. 1A

At V_{BAT}=2.7V, and I_{LOAD}=200mA, V_{BUS} would drop to:

$$V_{OUT} = 5.07 - 0.327 \cdot 0.2 = 5.005V$$
 EQ. 1B

PFM Mode

If $V_{BUS} > VREF_{BOOST}$ (nominally 5.07 V) when the minimum off-time has ended, the regulator enters PFM Mode. Boost pulses are inhibited until $V_{BUS} < VREF_{BOOST}$. The minimum on-time is increased to enable the output to pump up sufficiently with each PFM boost pulse. Therefore the regulator behaves like a constant on-time regulator, with the bottom of its output voltage ripple at 5.07 V in PFM Mode.

Table 17. Boost PWM Operating States

Mode	Description	Invoked When
LIN	Linear Startup	V _{BAT} > V _{BUS}
SS	Boost Soft-Start	$V_{BUS} < V_{BST}$
BST	Boost Operating Mode	V _{BAT} > UVLO _{BST} and SS Completed

Startup

When the boost regulator is shut down, current flow is prevented from V_{BAT} to $V_{\text{BUS}},$ as well as reverse flow from V_{BUS} to $V_{\text{BAT}}.$

LIN State

When EN rises, if V_{BAT} > UVLO_{BST}, the regulator first attempts to bring PMID within 400 mV of V_{BAT} using an internal 450 mA current source from VBAT (LIN State). If PMID has not achieved V_{BAT} – 400 mV after 560 μ s, a FAULT state is initiated.

SS State

When PMID > V_{BAT} - 400 mV, the boost regulator begins switching with a reduced peak current limit of about 50% of its normal current limit. The output slews up until V_{BUS} is within 5% of its set point; at which time, the regulation loop is closed and the current limit is set to 100%.

If the output fails to achieve 95% of its set point (V_{BST}) within 128 μs , the current limit is increased to 100%. If the output fails to achieve 95% of its set point after this second 384 μs period, a fault state is initiated.

BST State

This is the normal operating mode of the regulator. The regulator uses a minimum $t_{\text{OFF}}\text{-minimum}\ t_{\text{ON}}$ modulation scheme. The minimum t_{OFF} is proportional to $\frac{V_{\text{IN}}}{V_{\text{OUT}}}$, which

keeps the regulator's switching frequency reasonably constant in CCM. $t_{\text{ON(MIN)}}$ is proportional to V_{BAT} and is a higher value if the inductor current reached 0 before $t_{\text{OFF(MIN)}}$ in the prior cycle.

To ensure the VBUS does not pump significantly above the regulation point, the boost switch remains off as long as $FB > V_{REF}$.

Boost Faults

If a BOOST fault occurs:

- 1. The STAT pin pulses.
- 2. OPA MODE bit is reset.
- 3. The power stage is in High-Impedance Mode.
- 4. The FAULT bits (REG0[2:0]) are set per Table 18.

Restart After Boost Faults

If boost was enabled with the OPA_MODE bit and OTG_EN=0, Boost Mode can only be enabled through subsequent I²C commands since OPA_MODE is reset on boost faults. If OTG_EN=1 and the OTG pin is still ACTIVE (see Table 16), the boost restarts after a 5.2 ms delay, as shown in Figure 44. If the fault condition persists, restart is attempted every 5 ms until the fault clears or an I²C command disables the boost.

Table 18. Fault Bits During Boost Mode

Fa	ault Bit		Foult Description					
B2	В1	В0	Fault Description					
0	0	0	Normal (no fault)					
0	0	1	V _{BUS} > VBUS _{OVP}					
0	1	0	V_{BUS} fails to achieve the voltage required to advance to the next state during soft-start or sustained (>50 μ s) current limit during the BST state.					
0	1	1	V _{BAT} < UVLO _{BST}					
1	0	0	N/A: This code does not appear.					
1	0	1	Thermal shutdown					
1	1	0	Timer fault; all registers reset.					
1	1	1	N/A: This code does not appear.					

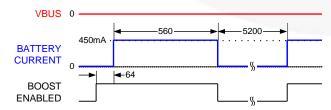


Figure 44. Boost Response Attempting to Start into V_{BUS} Short Circuit (Times in μs)

VREG Pin

The VREG pin on FAN5400 - FAN5402 provides a voltage protected from over-voltage surges on VBUS, which can be used to run auxiliary circuits. This voltage is essentially a current-limited replica of PMID. The maximum voltage on this node is 5.9 V.

FAN5403-FAN5405 provide a 1.8 V regulated output on this pin, which can be disabled through l^2C by setting the DIS_VREG bit (REG5[6]). VREG can supply up to 2 mA. This circuit, which is powered from PMID, is enabled only when PMID > V_BAT and does not drain current from the battery. During boost, V_REG is off. It is also off when the HZ_MODE bit (REG1[1])=1.

Monitor Register (Reg10h)

Additional status monitoring bits enable the host processor to have more visibility into the status of the IC. The monitor bits are real-time status indicators and are not internally debounced or otherwise time qualified.

The state of the MONITOR register bits listed in High-Impedance Mode are only valid when V_{BUS} is valid.

Table 19. MONITOR Register Bit Definitions

BIT#	NAME	S ⁻	Active When						
DII#	NAME	0	1	Active when					
MONITOR Address 10h									
7	ITERM_CMP	V _{CSIN} - V _{BAT} < V _{ITERM}	V _{CSIN} - V _{BAT} > V _{ITERM}	Charging with TE=1					
/	TIERIVI_CIVIP	V _{CSIN} – V _{BAT} < 1mV	V _{CSIN} - V _{BAT} > 1mV	Charging with TE=0					
		V _{BAT} < V _{SHORT}	V _{BAT} > V _{SHORT}	Charging					
6	VBAT_CMP	$V_{BAT} < V_{LOWV}$	$V_{BAT} > V_{LOWV}$	High-Impedance Mode					
		V _{BAT} < UVLO _{BST}	V _{BAT} > UVLO _{BST}	Boosting					
5	LINCHG	Linear Charging Not Enabled	Linear Charging Enabled	Charging					
4	T_120	T _J < 120°C	T _J > 120°C						
3	ICHG	Charging Current Controlled by I _{CHARGE} Control Loop	Charging Current Not Controlled by I _{CHARGE} Control Loop	Charging					
2	IBUS	I _{BUS} Limiting Charging Current	Charge Current Not Limited by I _{BUS}	Charging					
1	VBUS_VALID	V _{BUS} Not Valid	V _{BUS} is Valid	V _{BUS} > V _{BAT}					
0	CV	Constant Current Charging	Constant Voltage Charging	Charging					

I²C Interface

The FAN540X's serial interface is compatible with Standard, Fast, Fast Plus, and High-Speed Mode I²C-Bus® specifications. The FAN540X's SCL line is an input and its SDA line is a bi-directional open-drain output; it can only pull down the bus when active. The SDA line only pulls LOW during data reads and when signaling ACK. All data is shifted in MSB (bit 7) first.

Slave Address

Table 20. I²C Slave Address Byte

Part Types	7	6	5	4	3	2	1	0
FAN5400-FAN5404	1	1	0	1	0	1	1	R/W
FAN5405		1	0	1	0	1	0	R/W

In hex notation, the slave address assumes a 0 LSB. The hex slave address for the FAN5405 is D4h and is D6h for all other parts in the family.

Bus Timing

As shown in Figure 45, data is normally transferred when SCL is LOW. Data is clocked in on the rising edge of SCL. Typically, data transitions shortly at or after the falling edge of SCL to allow ample time for the data to set up before the next SCL rising edge.

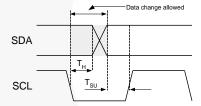


Figure 45. Data Transfer Timing

Each bus transaction begins and ends with SDA and SCL HIGH. A transaction begins with a START condition, which is defined as SDA transitioning from 1 to 0 with SCL HIGH, as shown in Figure 46.

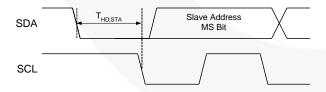


Figure 46. Start Bit

A transaction ends with a STOP condition, which is defined as SDA transitioning from 0 to 1 with SCL HIGH, as shown in Figure 47.

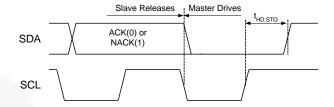


Figure 47. Stop Bit

During a read from the FAN540X (Figure 50), the master issues a Repeated Start after sending the register address and before resending the slave address. The Repeated Start is a 1-to-0 transition on SDA while SCL is HIGH, as shown in Figure 48.

High-Speed (HS) Mode

The protocols for High-Speed (HS), Low-Speed (LS), and Fast-Speed (FS) Modes are identical except the bus speed for HS Mode is 3.4 MHz. HS Mode is entered when the bus master sends the HS master code 00001XXX after a start condition. The master code is sent in Fast or Fast Plus Mode (less than 1MHz clock); slaves do not ACK this transmission.

The master then generates a repeated start condition (Figure 48) that causes all slaves on the bus to switch to HS Mode. The master then sends I²C packets, as described above, using the HS Mode clock rate and timing.

The bus remains in HS Mode until a stop bit (Figure 47) is sent by the master. While in HS Mode, packets are separated by repeated start conditions (Figure 48).

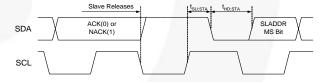


Figure 48. Repeated Start Timing

Read and Write Transactions

The figures below outline the sequences for data read and write. Bus control is signified by the shading of the packet,

defined as Master Drives Bus and Slave Drives Bus All addresses and data are MSB first.

Table 21. Bit Definitions for Figure 49, Figure 50

Symbol	Definition
S	START, see Figure 46.
А	ACK. The slave drives SDA to 0 to acknowledge the preceding packet.
Ā	NACK. The slave sends a 1 to NACK the preceding packet.
R	Repeated START, see Figure 48
Р	STOP, see Figure 47



Figure 49. Write Transaction



Figure 50. Read Transaction

Register Descriptions

The FAN5400-FAN5402 have seven user-accessible registers; the FAN5403-05 have an additional two registers, as defined in Table 22.

Table 22. I²C Register Address

IC	Register	Address Bits								
lC lC	Name	REG#	7	6	5	4	3	2	1	0
	CONTROL0	0	0	0	0	0	0	0	0	0
	CONTROL1	1	0	0	0	0	0	0	0	1
	OREG	2	0	0	0	0	0	0	1	0
ALL	IC_INFO	03 or 3Bh	0	0	0	0	0	0	1	1
	IBAT	4	0	0	0	0	0	1	0	0
FAN5403-FAN5405	SP_CHARGER	5	0	0	0	0	0	1	0	1
FAIND405-FAIND405	SAFETY	6	0	0	0	0	0	1	1	0
ALL	MONITOR	10h	0	0	0	0	1	0	1	0

Table 23. Register Bit Definitions

This table defines the operation of each register bit for all IC versions. Default values are in **bold** text.

Bit	Name	Value	Туре		Description	
CONT	ROL0		•	Register Address: 00	Default Value=X1XX 0XXX	
7	TMR_RST	1	W	Writing a 1 resets the t _{32S} timer; writing a 0 has no effect		
′	OTG	'	R	Returns the OTG pin level (1=HIC	GH)	
6 EN_STAT		U R/VV		OW during charging; STAT pin still pulses to		
		1		Enables STAT pin LOW when IC is charging		
		00	R	Ready		
F. 4	CTAT	01		Charge in progress		
5:4	STAT	10		Charge done		
		11		Fault		
3	POOST	0	R	IC is not in Boost Mode		
3	BOOST	1	180	IC is in Boost Mode		
2:0	FAULT		R	Fault status bits: for Charge Mod	le, see Table 13; for Boost Mode: see Table 18	

Table 23. Register Bit Definitions (Continued)

Bit	Name	Value	Туре	Description				
CONT	ROL1			Register Address: 01	Default Value=0011 0000 (30h)			
7:6	I _{INLIM}		R/W	Input current limit, see Table 7				
	00	00	R/W	3.4 V				
- 4		01		3.5 V				
5:4	V_{LOWV}	10		3.6 V	Weak battery voltage threshold			
		11		3.7 V				
		0	R/W	Disable charge current termination	n '			
3	TE	1		Enable charge current termination				
		0	R/W	Charger enabled				
2	CE	1		Charger disabled				
	117 MODE	0	R/W	Not High-Impedance Mode				
1	HZ_MODE	1		High-Impedance Mode	0 T-14- 40			
	004 44005	0	R/W	Charge Mode	See Table 16			
0	OPA_MODE	1		Boost Mode				
OREG		7		Register Address: 02	Default Value=0000 1010 (0Ah)			
7:2	OREG	X	R/W	Charger output "float" voltage; programmable from 3.5 to 4.44 V in 20 mV increments; defaults to 000010 (3.54 V) , see Table 3				
		0	R/W	OTG pin active LOW				
1	OTG_PL	1		OTG pin active HIGH				
	070 511	0	R/W	Disables OTG pin				
0	OTG_EN	1		Enables OTG pin				
IC_INI	O		I	Register Address: 03 or 3B	Default Value=100X XXXX			
7:5	Vendor Code	100	R	Identifies Fairchild Semiconductor as	s the IC supplier			
4:3	PN		R	Part number bits, see the Ordering In	nfo on page 1			
2:0	REV		R	IC Revision, revision 1.X, where X is	the decimal of these three bits			
IBAT			•	Register Address: 04	Default Value=1000 1001 (89h)			
7	RESET	1	W	Writing a 1 resets charge parameters, except the Safety register (Reg6), to the defaults: writing a 0 has no effect; read returns 1				
6:4	IOCHARGE	Table 5	R/W	Programs the maximum charge current, see Table 5				
3	Reserved	1	R	Unused				
2:0	ITERM	Table 6	R/W	Sets the current used for charging termination, see Table 6				

Table 23. Register Bit Definitions (Continued)

SP_CI	HARGER (FANS	403 – FAN	5405)	Register Address: 05 Default Value=001X X100		
7	Reserved	0	R	Unused		
	DIC VIDEO	0	R/W	1.8 V regulator is ON		
6	DIS_VREG	1		1.8 V regulator is OFF		
		0	R/W	Output current is controlled by IOCHARGE bits		
5	IO_LEVEL	1		Voltage across R_{SENSE} for output current control is set to 22.1 mV (325 mA for R_{SENSE} =68 m Ω , 221 mA for 100 m Ω)		
4	CD.	0	R	Special charger is not active (V _{BUS} is able to stay above V _{SP})		
4	SP	1		Special charger has been detected and V _{BUS} is being regulated to V _{SP}		
2	ENLLEVEL	0	R	DISABLE pin is LOW		
3	EN_LEVEL 1			DISABLE pin is HIGH		
2:0	0 VSP Table 8 R/W S			Special charger input regulation voltage, see Table 8		
SAFETY (FAN5403 – FAN5405)			Register Address: 06 Default Value=0100 0000 (40h)			
7	Reserved	0	R	Bit disabled and always returns 0 when read back		
6:4	ISAFE	Table 9	R/W	Sets the maximum I _{OCHARGE} value used by the control circuit, see Table 9		
3:0	VSAFE	Table 10	R/W	Sets the maximum V _{OREG} used by the control circuit, see Table 10		
MONI	TOR			Register Address: 10h (16) See Table 19		
7	ITERM_CMP	7	R	Real-time ITERM comparator output: 1 when VRSENSE > ITERM reference. Dynamic system loads can cause this bit to toggle between 0 and 1.		
6	VBAT_CMP		R	Output of VBAT comparator		
5	LINCHG		R	30 mA linear charger ON		
4	T_120	See	R	Thermal regulation comparator; when=1 and T_145=0, the charge current is limited to 22.1 mV across R _{SENSE}		
3	ICHG	Table 19	R	0 indicates the I _{CHARGE} loop is controlling the battery charge current		
2	IBUS		R	0 indicates the I _{BUS} (input current) loop is controlling the battery charge current		
1	VBUS_VALID		R	1 indicates V _{BUS} has passed validation and is capable of charging		
0	CV		R	1 indicates the constant-voltage loop (OREG) is controlling the charger and all current limiting loops have released		

PCB Layout Recommendations

Bypass capacitors should be placed as close to the IC as possible. In particular, the total loop length for CMID should be minimized to reduce overshoot and ringing on the SW, PMID, and VBUS pins. All power and ground pins must be

routed to their bypass capacitors using top copper if possible. Copper area connecting to the IC should be maximized to improve thermal performance.

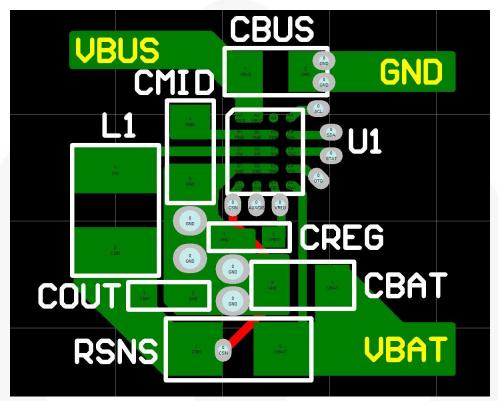
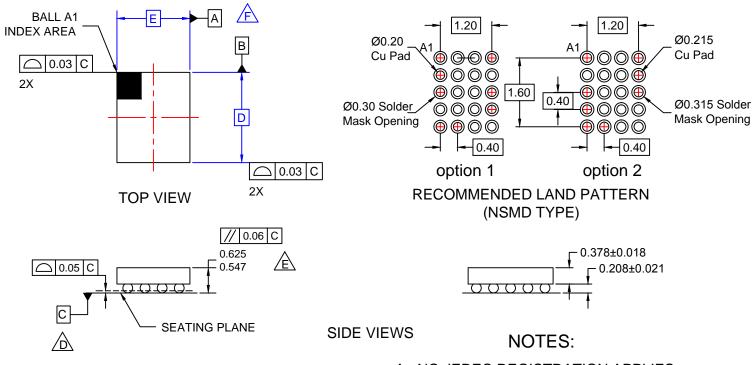


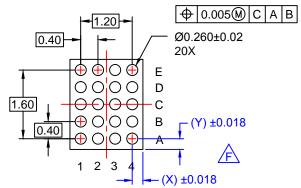
Figure 51. PCB Layout Recommendations

The following information applies to the WLCSP package dimensions on the next page:

Product-Specific Dimensions

Product	D	E	X	Υ
FAN540xUCX	1.960 ±0.030	1.870 ±0.030	0.335	0.180





BOTTOM VIEW

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 2009.
- DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- EXPACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).
- FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
- G. DRAWING FILNAME: MKT-UC020AArev4.



ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see any inability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and ex

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Battery Management category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

MP26121DQ-LF-P NCP1855FCCT1G FAN54063UCX LC05132C01NMTTTG SN2040DSQR ME4075AM5G AP5054HTCER XPD977B

XPD977B18 4056H DW01 DW06 CM1002-UD CM1002-W CM1002-X CM1002-Y CM1006-B CM1006-Q CM1006-WB CM1006-LCD

CM1006-LBD CM1006-WF CM1006-LF CM1006-WG CM1006-WH CM1006-LG CM1003-S02BD CM1003-S09EA CM1003-S10ED

CM1003-S11ED CM1003-S12BC CM1003-S13CC CM1003-S24BC CM1003-S26BC CM1003-WAD CM1003-BBD CM1003-BFD

CM1003-BND CM1003-BLD CM1003-DAD CM1003-BMD CM1003-BPD CM1003-BKD CM1003-BAE CM1003-BHE CM1102B-FF

CM1102B-FD CM1102B-GD CM1112-DAE CM1112-DBE